

# MBF Plastic-Encapsulate Bridge Rectifier

## General Purpose Bridge Rectifier

### Features:

- $I_{F(AV)}$  2A
- $V_{RRM}$  200V-1000V
- High surge current capability
- Glass passivated chip

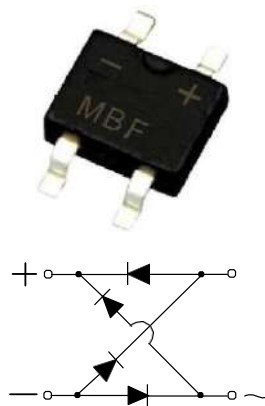
### Applications:

- General purpose 1 phase Bridge rectifier applications

### Marking

- MB2XF
- X : From 2 To 10

MBF



### Limiting Values (Absolute Maximum Rating)

Item	Symbol	Unit	Conditions	MB				
				22F	24F	26F	28F	210F
Repetitive Peak Reverse Voltage	$V_{RRM}$	V		200	400	600	800	1000
Maximum RMS Voltage	$V_{RMS}$	V		140	280	420	560	700
Average Rectified Output Current	$I_o$	A	60Hz sine wave, R-load, $T_a=115^{\circ}C$ On alumina substrate	2.0				
Surge(Non-repetitive)Forward Current	$I_{FSM}$	A	8.3ms sine wave, 1 cycle, $T_j=25^{\circ}C$	55				
			1.0ms sine wave, 1 cycle, $T_j=25^{\circ}C$	75				
Current Squared Time	$I^2t$	$A^2S$	$1ms \leq t < 8.3ms$ $T_j=25^{\circ}C$ , Rating of per diode	8.03				
Operation Junction and Storage Temperature Range	$T_j, T_{stg}$	$^{\circ}C$		-55 ~ +150				

### Electrical Characteristics (T=25°C Unless otherwise specified)

Item	Symbol	Unit	Test Condition	Max
Peak Forward Voltage	$V_{FM}$	V	$I_{FM}=1.0A$ , Pulse measurement, Rating of per diode	0.95
Peak Reverse Current	$I_{RRM}$	$\mu A$	$V_{RM}=V_{RRM}$ , Pulse measurement, Rating of per diode	5
Thermal Resistance	$R_{\theta J-A}$	$^{\circ}C/W$	Between junction and ambient, On alumina substrate	25
	$R_{\theta J-L}$		Between junction and lead	18
	$R_{\theta J-C}$		Between junction and case	18

### Typical Characteristics

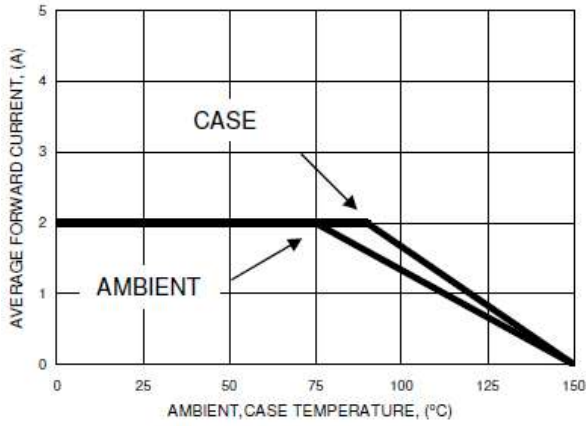


FIG.1- FORWARD CURRENT DERATING CURVE

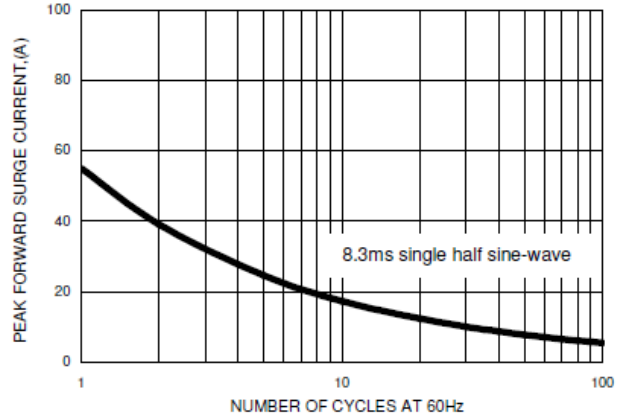


FIG.2- MAXIMUM NON-REPETITIVE SURGE CURRENT

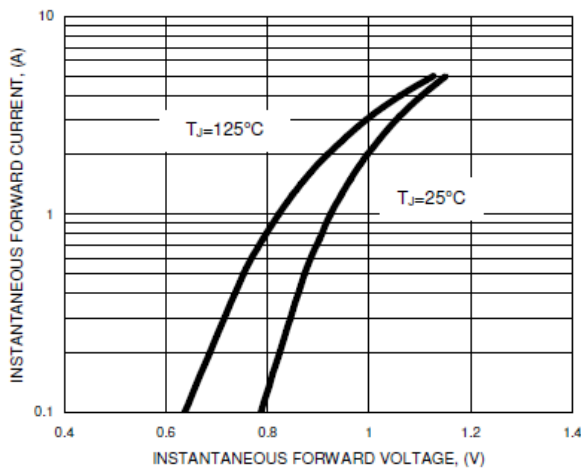


FIG.3- TYPICAL FORWARD CHARACTERISTICS

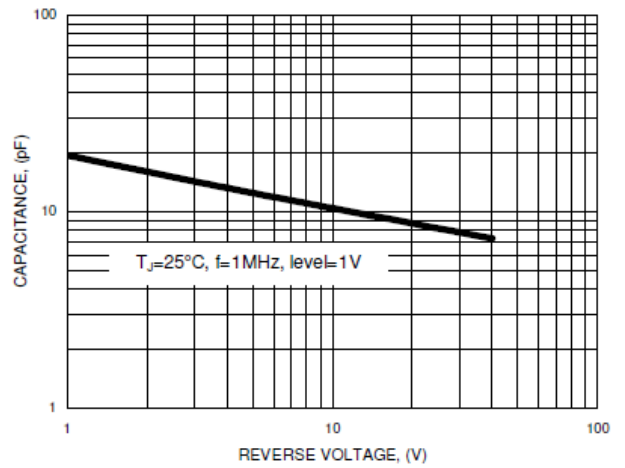


FIG.4- TYPICAL JUNCTION CAPACITANCE

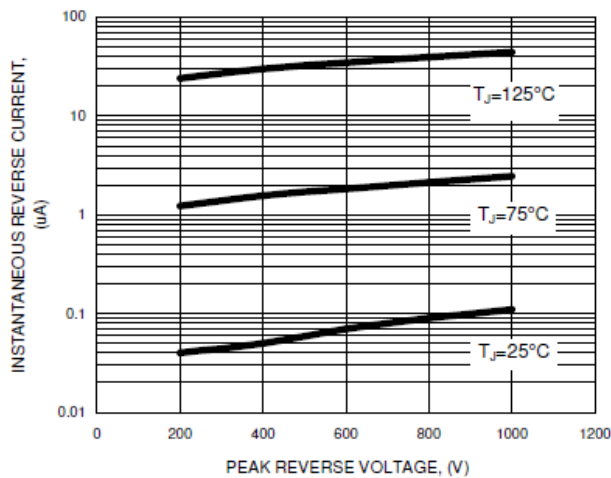
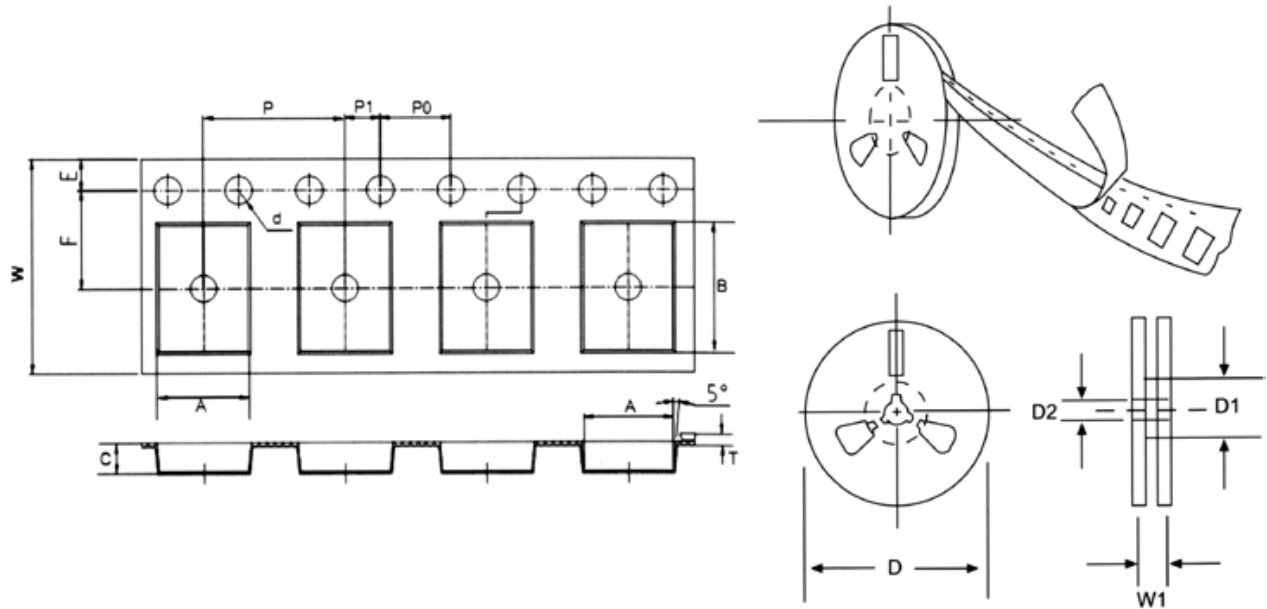


FIG.5- TYPICAL REVERSE CHARACTERISTICS



## Reel Taping Specifications For Surface Mount Devices-MBF



**FIG: CONFIGURATION OF SURFACE MOUNTED DEVICES TAPING**

ITEM	SYMBOL	MBF mm(inch)
Carrier width	A	5.02±0.1(0.198±0.004)
Carrier length	B	7.15±0.1(0.281±0.004)
Carrier depth	C	1.65±0.1(0.074±0.004)
Sprocket hole	d	1.55±0.05(0.061±0.002)
Reel outside diameter	D	279±2.0 (11± 0.079)
Reel inner diameter	D1	75 ±1.0 ( 2.95 ±0.039)
Feed hole diameter	D2	13±0.5(0.512±0.020)
Strocket hole position	E	1.75±0.1(0.069±0.004)
Punch hole position	F	5.50±0.1(0.217±0.002)
Punch hole pitch	P	8.0±0.1(0.315±0.004)
Sprocket hole pitch	P0	4.0±0.1(0.157±0.004)
Embossment center	P1	2.0±0.1(0.079±0.004)
Totall tape thickness	T	0.20-0.70(0.008-0.028)
Tape width	W	12.0±0.3/-0.1(0.472±0.004)
Reel width	W1	16.8±2.0(0.661±0.079)

NOTE: Devices are packde in accordance with EIA standard RS-481-A and specification given above.